

Preliminary Results with Miniature Microstrip p-type Detectors after Neutron Irradiation to SLHC Doses

G. Casse, University of Liverpool

1



OUTLINE

- Summary of previous results with 24GeV/c protons
- New preliminary results with neutron irradiated devices



Accepted facts about Si segmented devices for increased radiation hardness:

N-side read-out on n-type substrates gives the main advantage (ATLAS and CMS pixels, LHCb-VELO microstrips).

Comparison n to p-side read out





Implementing n-side readout on p-type silicon

The n-side read-out can be equally well implemented on a p-type substrate and keep the same advantages for CCE after irradiation and exhibiting two additional advantages compared to the n-type bulk.

• The p-type bulk doesn't invert, so the junction side will always be on the same side before and after irradiation

•The p-type substrate devices don't required backplane processing, which turns out being cheaper (40-50%) than the n-type. This argument can be very important for large area coverage.





Facts about Si segmented devices for increased radiation hardness: n strip read-out on p-type silicon

University of Liverpool

24 GeV/c proton irradiation in CERN/PS (thanks to M. Glaser)

After 7.510^{15} p cm⁻² 7000e are collected at 900V.

The charge collected at these doses is determined predominantly by trapping. At low temperature the noise can be controlled.





Fig. 1 Noise as a function of the applied voltage for the three different irradiation doses. The pre-irradiation value is about 35 ADC counts, similar to the value found after irradiation.

G. Casse, ATLAS Tracker Upgrade Workshop , Liverpool, 06-08 December 2006



Annealing after proton irradiation

University of Liverpool

The signal doesn't degrade significantly with annealing time up to 7y equivalent at room temperature (while V_{FD} is expected to rise from 2.8kV to 12kV)!



G. Casse, ATLAS Tracker Upgrade Workshop , Liverpool, 06-08 December 2006 6



Below is the figure for the charge collection degradation after proton irradiation of miniature μ -strip detectors read-out with 40MHz analogue electronics. According to what observed above, this figure is not significantly changing with time at 20°C after irradiation.



G. Casse, ATLAS Tracker Upgrade Workshop , Liverpool, 06-08 December 2006



The radiation damage in SLHC will be due to particles emerging from the interactions and to backscattered neutrons. The radius at which the two contributions are about equal is between 20-25 cm. For further radii the neutron contribution becomes dominating. The μ -strip detectors therefore will be operated in an area where the neutron contributes to the radiation damage for more than 50%.

It is therefore necessary to prove the radiation resistance of the μ -strip devices with neutron irradiation as well as with charged particles.



Neutron irradiations

A few μ -strip detectors (1X1 cm²) made by Micron on 140 and 300 μ m thick high resistivity (>10kW cm) p-type wafers and irradiated in the Ljubljana research reactor to 0.5, 1.6 and 3 10¹⁵ n cm⁻² (thanks V. Cindro, M. Mikuz).

Two detectors irradiated to 1.6 and 3 10¹⁵ n cm⁻² have been measured with LHC speed analogue electronics (SCT128A). The higher dose detector has also been measured after accelerated annealing to almost 3 years room temperature equivalent (two steps at 60°C and two at 80°C).



Neutron irradiations: 1.6-10¹⁵ n cm⁻²

PRELIMINARY





Neutron irradiations: 3-10¹⁵ n cm⁻²



PRELIMINARY

G. Casse, ATLAS Tracker Upgrade Workshop , Liverpool, 06-08 December 2006 11



Neutron irradiations: 3-10¹⁵ n cm⁻² Annealing PRELIMINARY





Neutron and proton irradiations summary





Neutron irradiations

More μ -strip detectors (1X1 cm²) made by CNM Barcelona on 300 μ m thick high resistivity p-type wafers were irradiated in Ljubljana to various fluences. They have been measured in Valencia and Barcelona with a different method from the measurements just shown: the strips were connected to a common metal rail (*diode* configuration) and read-out with a highbandwidth current amplifier.



Neutron irradiations: comparison "diode" vs µ-strips





Conclusions

- New (and preliminary) results with µ-strip detectors irradiated with neutrons to SLHC fluences and read-out with LHC-speed electronics are here shown. The collected charge seems to scale with the NIEL function. Need fresh system calibration to confirm/correct the numbers here presented. Long term annealing doesn't effect substantially the measured signal, at least within a practical time for operations.
- The differences found with other measurements can be due to the difference in the read-out scheme (individual strips or diode configuration)